



Transport in twisted bilayer graphene

- Introduction for twisted bilayer graphene (TBG)
- Non-linear Hall effect (NHE) at non-magic angle
- Quantum anomalous Hall (QAH) and semimetal at magic angle

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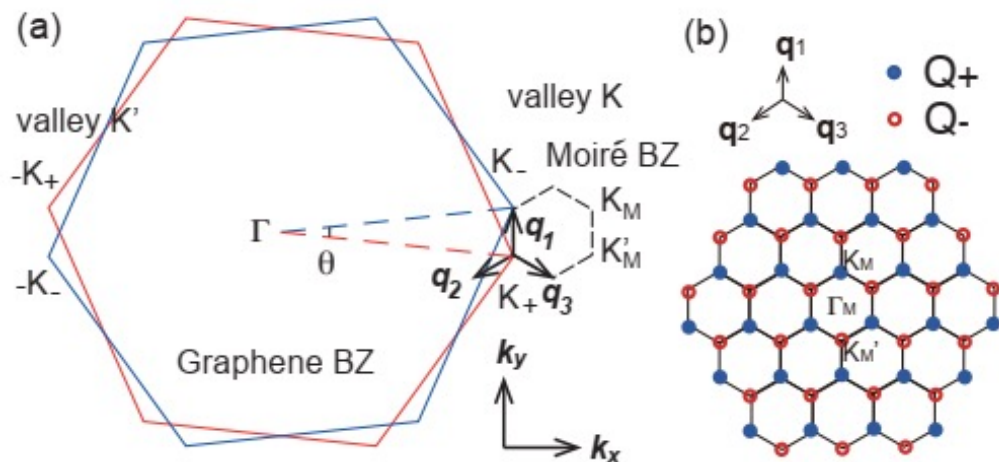
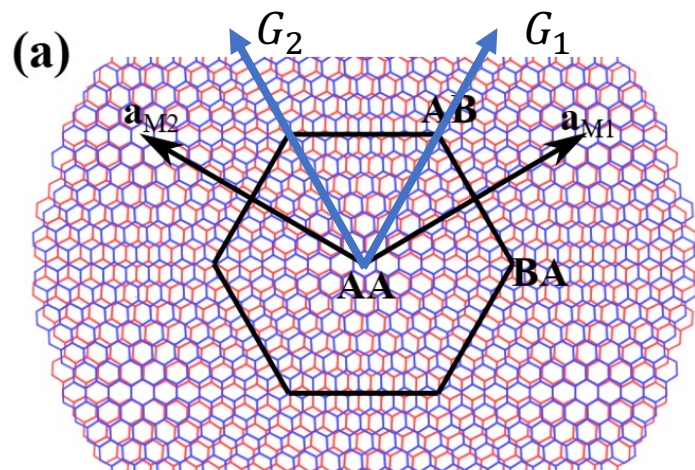


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BM model for TBG

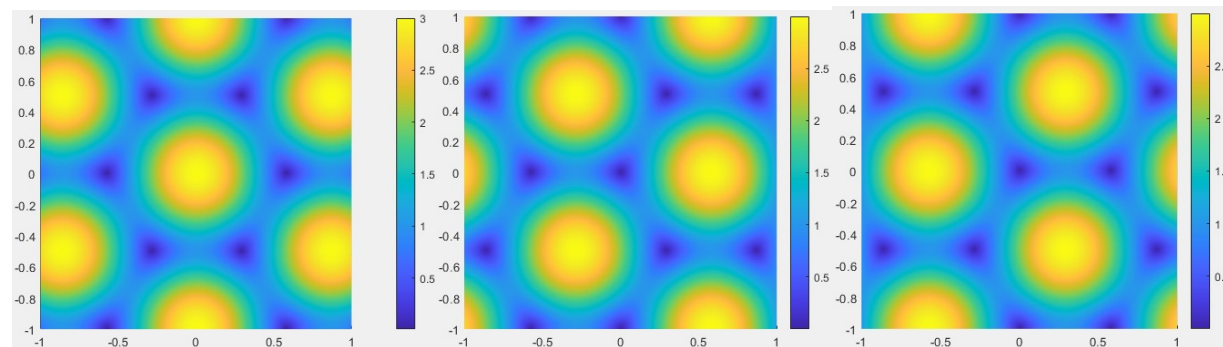


Moiré bands in twisted double-layer graphene, Rafi Bistritzer and Allan H. MacDonald. PNAS 108, 12233 (2011)

TBG I-V, B. Andrei Bernevig, Zhi-Da Song, etc. PRB (2021)...

$$H(r) = -i\mathbf{v}_F \begin{pmatrix} \partial_r \cdot \boldsymbol{\sigma} & 0 \\ 0 & \partial_r \cdot \boldsymbol{\sigma} \end{pmatrix} + \begin{pmatrix} 0 & T(r) \\ T^\dagger(r) & 0 \end{pmatrix}$$

$$T(r) = \sum_{j=1}^3 e^{-iq_j \cdot r} \cdot \begin{pmatrix} u_0 & u_1 e^{-i\frac{2\pi(j-1)}{3}} \\ u_1 e^{i\frac{2\pi(j-1)}{3}} & u_0 \end{pmatrix}$$

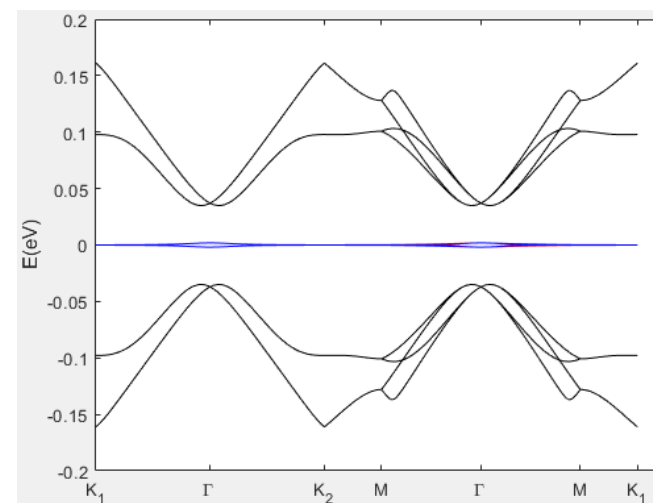


AA hopping

BA hopping

AB hopping

$$q_1 = \frac{G_2 + G_1}{3}, q_2 = \frac{G_2 - 2G_1}{3}, q_3 = \frac{G_1 - 2G_2}{3}$$



$$(\theta, v_F/a_0, u_0, u_1) = (1.08^\circ, 2.38\text{eV}, 0.08\text{eV}, 0.11\text{eV})$$



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Semiclassical Boltzmann equation

$$\frac{f - f_0}{-\tau} = \partial_t f + \dot{\mathbf{k}} \cdot \nabla_{\mathbf{k}} f$$

$$\dot{\mathbf{k}} = q\mathbf{E}(t) = q\mathbf{E}_k e^{i\omega t}$$

$$j_\alpha = q \int f(k) v_\alpha$$

$$v_\alpha \approx \partial_\alpha \varepsilon - q(\mathbf{E} \times \boldsymbol{\Omega})_\alpha$$



$$f^{(0)} = f_0 = \frac{1}{e^{\beta\varepsilon} + 1}$$

$$f^{(1)} = \frac{-q\tau}{1 + i\omega\tau} \mathbf{E}_k e^{i\omega t} \partial_{\mathbf{k}} f^{(0)}$$

$$f^{(2)} = \frac{(q\tau)^2 \mathbf{E}_{k_1} \mathbf{E}_{k_2} e^{i2\omega t}}{(1 + i2\omega\tau)(1 + i\omega\tau)} \partial_{k_1} \partial_{k_2} f^{(0)}$$

$$j_\alpha^{(0)} = q \int f^{(0)} \partial_\alpha \varepsilon = 0$$

$$j_\alpha^{(1)} = -q^2 \int f^{(0)} (\mathbf{E} \times \boldsymbol{\Omega})_\alpha + q \int f^{(1)} \partial_\alpha \varepsilon$$

$$j_\alpha^{(2)} = -q^2 \int f^{(1)} (\mathbf{E} \times \boldsymbol{\Omega})_\alpha + q \int f^{(2)} \partial_\alpha \varepsilon$$

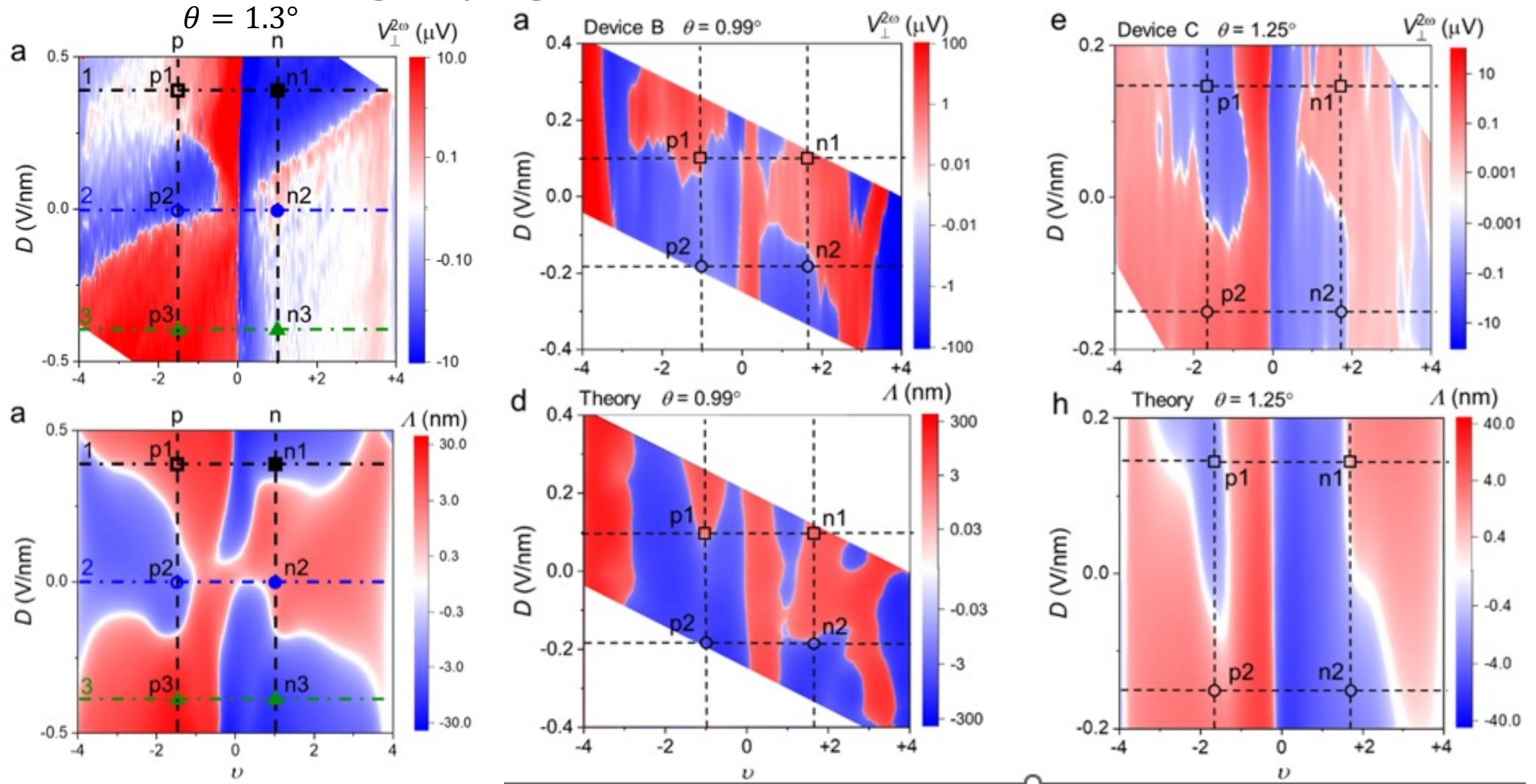
$$\sigma_{\alpha\beta} = -q^2 \epsilon_{\alpha\beta\gamma} \int f^{(0)} \Omega_\gamma + \frac{q^2 \tau}{1 + i\omega\tau} \int f^{(0)} \partial_\alpha \partial_\beta \varepsilon$$

$$\chi_{\alpha\beta\gamma} = -\frac{q^3 \tau}{1 + i\omega\tau} \epsilon_{\alpha\beta\eta} \int f^{(0)} \partial_\gamma \Omega_\eta + \frac{q^3 \tau^2}{(1 + i2\omega\tau)(1 + i\omega\tau)} \int f^{(0)} \partial_\alpha \partial_\beta \partial_\gamma \varepsilon + (\beta \leftrightarrow \gamma)$$



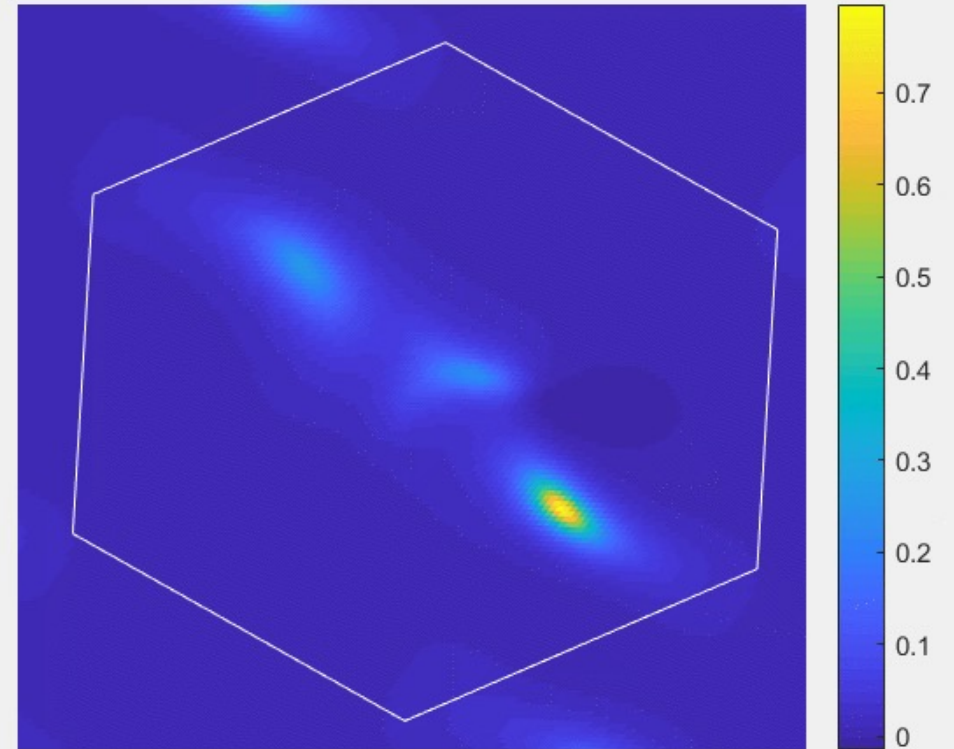
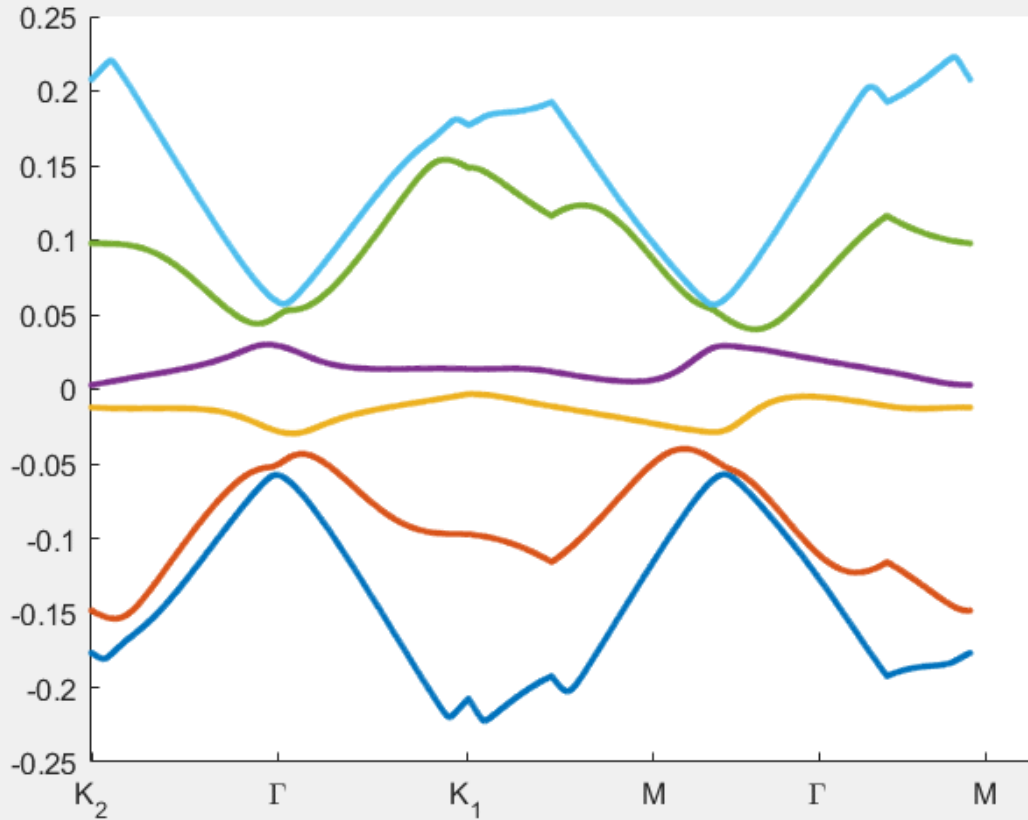
NHE tuning by gates

Intrinsic nonlinear Hall effect and gate-switchable Berry curvature sliding in twisted bilayer graphene, Meizhen Huang, Zefei Wu, Xu Zhang, etc. arXiv:2212.12666 (2022)



Berry curvature hotspot sliding

$\theta = 1.3^\circ$, strain $\epsilon = 0.3\%$



$$\chi_{\alpha\beta\gamma} = -\frac{q^3\tau}{1+i\omega\tau}\epsilon_{\alpha\beta\eta}\int\left(\frac{\partial f_0}{\partial E}\right)\partial_\gamma E\cdot\Omega_\eta+(\beta\leftrightarrow\gamma)$$



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Chiral limit and symmetry

BM model review in momentum space

$$H^\tau(k) = v_F \begin{pmatrix} (k - K_-) \cdot \sigma & 0 \\ 0 & (k - K_+) \cdot \sigma \end{pmatrix} \delta_{k_1, k'_1} + \begin{pmatrix} 0 & U^\tau \\ U^{\tau\dagger} & 0 \end{pmatrix}$$

$$U^\tau = \begin{pmatrix} u_0 & u_1 \\ u_1 & u_0 \end{pmatrix} \delta_{k_1, k'_1} + \begin{pmatrix} u_0 & u_1 e^{-i\frac{2\pi}{3}} \\ u_1 e^{i\frac{2\pi}{3}} & u_0 \end{pmatrix} \delta_{k_1, k'_1 - G_1} + \begin{pmatrix} u_0 & u_1 e^{i\frac{2\pi}{3}} \\ u_1 e^{-i\frac{2\pi}{3}} & u_0 \end{pmatrix} \delta_{k_1, k'_1 - G_2} \quad (u_0 = 0 \text{ for chiral limit})$$

At chiral limit

$$\sigma_z H^\tau(k) \sigma_z = -H^\tau(k)$$

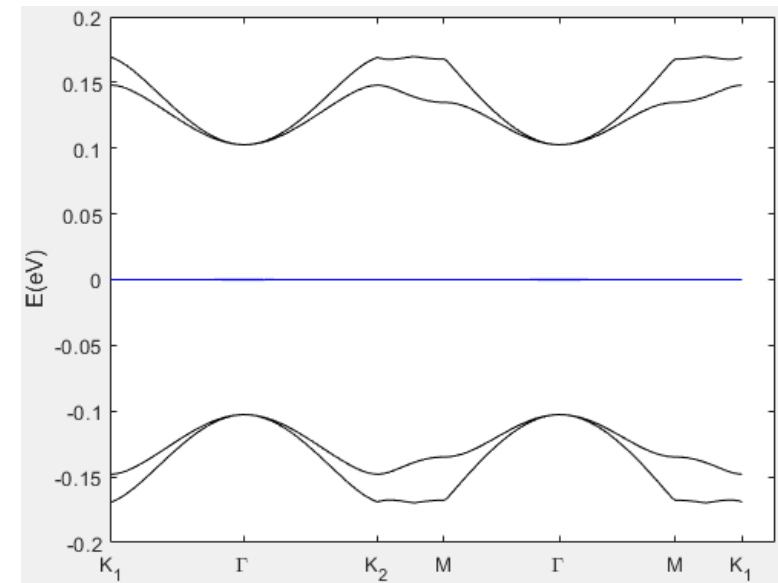
$$H^\tau(k) |\psi_E\rangle = E |\psi_E\rangle = 0 \quad (E = 0 \text{ for chiral limit flat bands})$$

$$H^\tau(k) \sigma_z |\psi_E\rangle = -E \sigma_z |\psi_E\rangle = 0$$

Diagonalize flat bands according to eigenvalue of σ_z (Equivalent to apply an hBN perturbation which gives two bands Chern number ± 1)

$$\begin{pmatrix} \langle \psi_1 | \sigma_z | \psi_1 \rangle & \langle \psi_1 | \sigma_z | \psi_2 \rangle \\ \langle \psi_2 | \sigma_z | \psi_1 \rangle & \langle \psi_2 | \sigma_z | \psi_2 \rangle \end{pmatrix} \Rightarrow \begin{cases} |\psi_+\rangle = |\psi_1\rangle + \sigma_z |\psi_1\rangle \\ |\psi_-\rangle = |\psi_1\rangle - \sigma_z |\psi_1\rangle \end{cases} \Rightarrow \begin{pmatrix} \langle \psi_+ | \sigma_z | \psi_+\rangle & \langle \psi_+ | \sigma_z | \psi_-\rangle \\ \langle \psi_- | \sigma_z | \psi_+\rangle & \langle \psi_- | \sigma_z | \psi_-\rangle \end{pmatrix} = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix}$$

(Chern basis)



Chiral limit and symmetry

Projected Coulomb interaction at flat chiral limit

$$H = \frac{1}{2\Omega} \sum_G \sum_{q \in mBZ} V(q+G) \delta\rho_{q+G} \delta\rho_{-q-G}$$

$$\delta\rho_{q+G} = \sum_{k,m,n,s,\tau} \lambda_{m,n,\tau}(k, k+q+G) \left(c_{k,m,s,\tau}^\dagger c_{k+q,n,s,\tau} - \frac{\nu+4}{8} \delta_{q,0} \delta_{m,n} \right)$$

$$= \sum_{k,m,n} \lambda_{m,n,\tau}(k, k+q+G) \left(c_{k,m,s,\tau}^\dagger c_{k+q,n,s,\tau} + c_{k,m,-s,\tau}^\dagger c_{k+q,n,-s,\tau} + \tilde{c}_{k,m,s,-\tau}^\dagger \tilde{c}_{k+q,n,s,-\tau} + \tilde{c}_{k,m,-s,-\tau}^\dagger \tilde{c}_{k+q,n,-s,-\tau} - \frac{\nu+4}{2} \delta_{q,0} \delta_{m,n} \right)$$

$$= \sum_{k,m} \lambda_{m,\tau}(k, k+q+G) \left(c_{k,m,s,\tau}^\dagger c_{k+q,m,s,\tau} + c_{k,m,-s,\tau}^\dagger c_{k+q,m,-s,\tau} + \tilde{c}_{k,m,s,-\tau}^\dagger \tilde{c}_{k+q,m,s,-\tau} + \tilde{c}_{k,m,-s,-\tau}^\dagger \tilde{c}_{k+q,m,-s,-\tau} - \frac{\nu+4}{2} \delta_{q,0} \right)$$

$C_{2z}P$ symmetry, $\lambda_{m,n,\tau}(k, k+q+G) = m \cdot n \cdot \lambda_{-m,-n,-\tau}(k, k+q+G)$

$$\tilde{c}_{k,-m,s,-\tau}^\dagger = m c_{k,m,s,-\tau}^\dagger$$

chiral limit
 $\langle \psi_+ | \psi_- \rangle = 0$

	τ, S	$\tau, -S$	$-\tau, S$	$-\tau, -S$
τ, S	$\lambda_{m,n,\tau}$			
$\tau, -S$		$\lambda_{m,n,\tau}$		
$-\tau, S$			$\lambda_{m,n,\tau}$	
$-\tau, -S$				$\lambda_{m,n,\tau}$

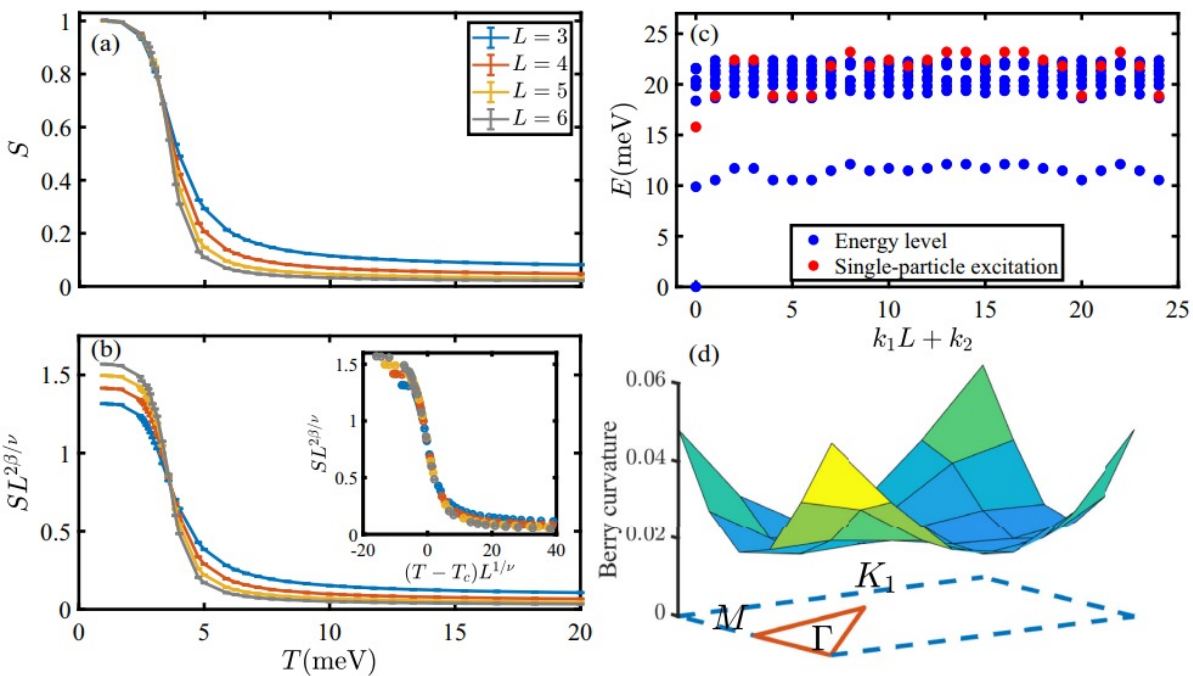
U(4)

chiral limit

	τ, S	$\tau, -S$	$-\tau, S$	$-\tau, -S$
τ, S	$\lambda_{m,\tau}$			
$\tau, -S$		$\lambda_{-m,\tau}$		
$-\tau, S$			$\lambda_{m,\tau}$	
$-\tau, -S$				$\lambda_{-m,\tau}$

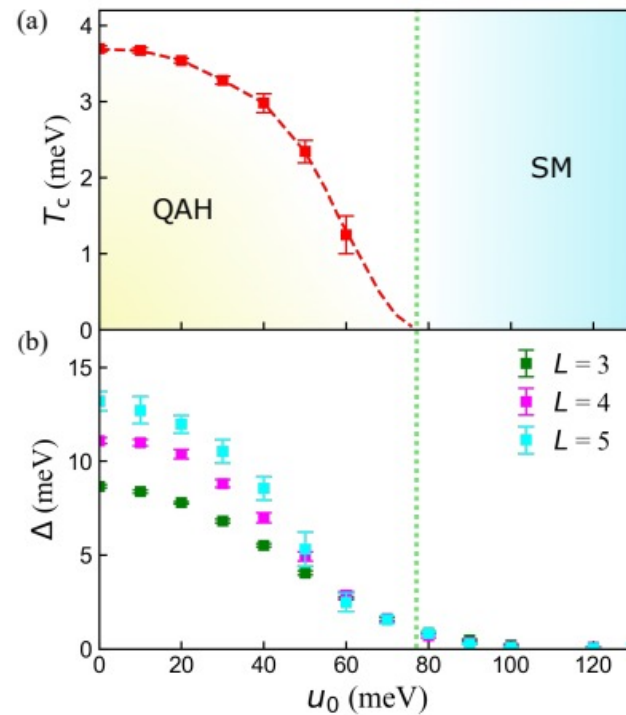
U(4) × U(4)

Assume spin-valley polarizing at $\nu = \pm 3$



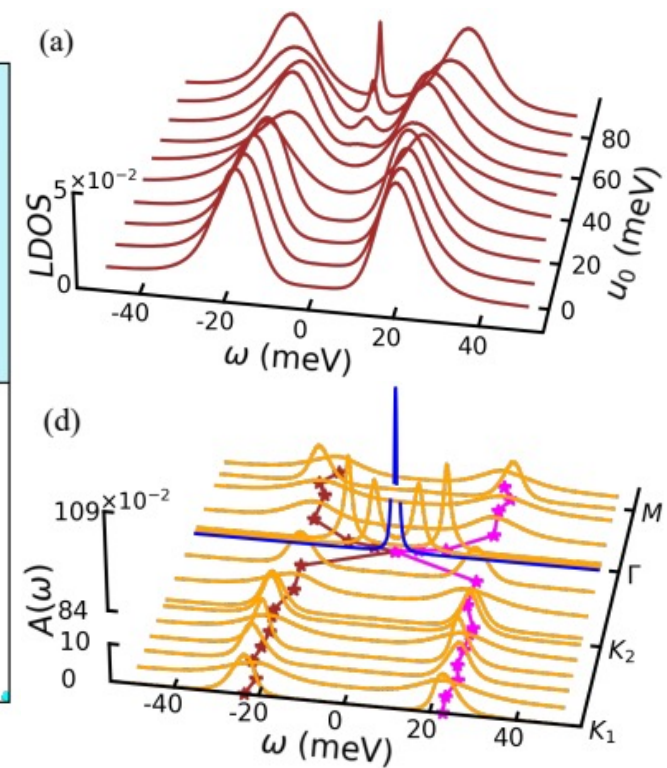
Flat-chiral limit $u_0 = 0$

Ground state: **Quantum anomalous Hall**



Flat band non-chiral $u_0 \neq 0$

Ground state: From **Quantum anomalous Hall** to **semimetal**

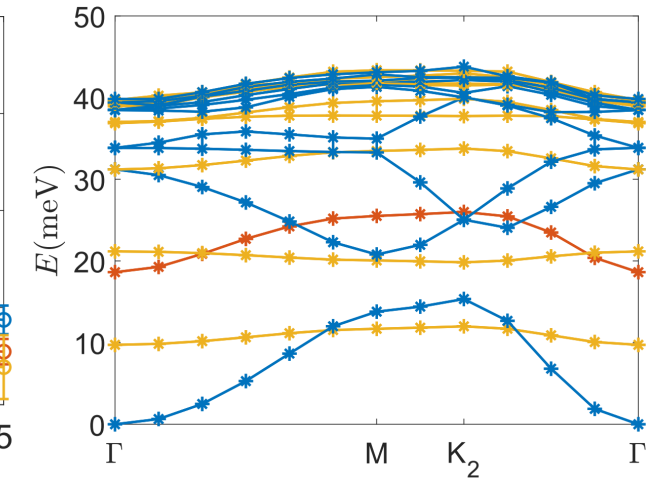
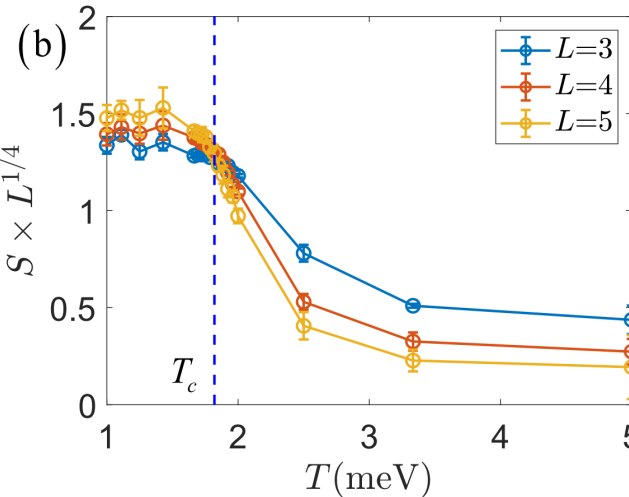
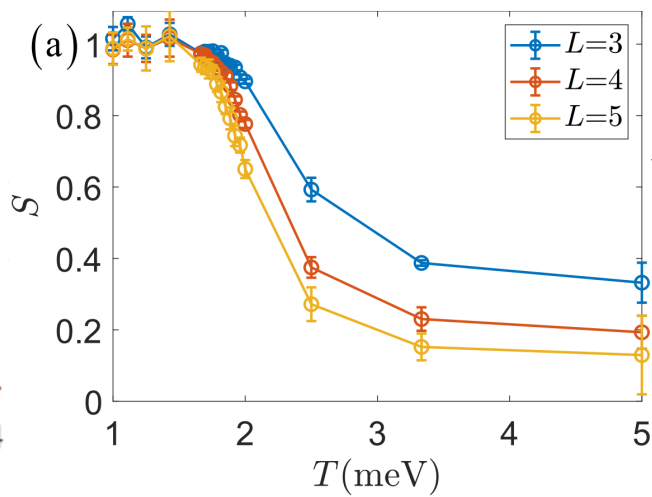
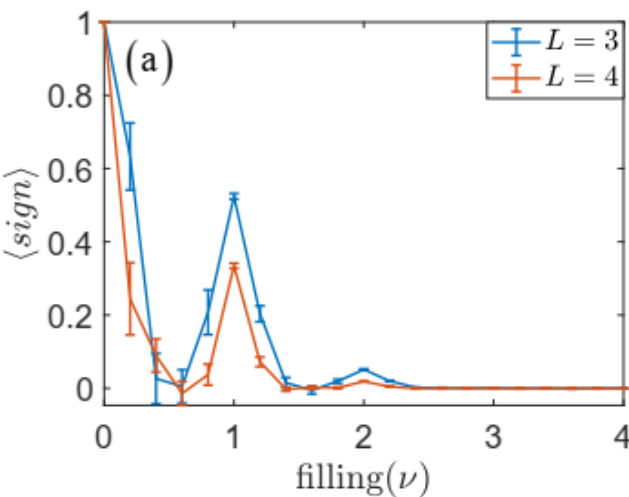


Chiral-flat band TBG at $\nu = \pm 1$

Polynomial sign bounds behavior at low temperature

$$\langle sign \rangle \geq \frac{g_{\nu=1}}{g_{\nu=0}} = \frac{\frac{(N+3)^2(N+2)^3(N+1)^2}{3!3!} + \frac{(N+3)(N+2)(N+1)}{3}}{\frac{(N+3)^2(N+2)^4(N+1)^2}{3!3!2!2!} + \frac{(N+3)^2(N+2)^2(N+1)^2}{3!3} + 2} \propto N^{-1}$$

Filling(ν)	Chiral($\gamma = 0$)
0	1
± 1	N^{-1}
± 2	N^{-2}
± 3	N^{-5}
± 4	N^{-8}



Polynomial sign problem and topological Mott insulator in twisted bilayer graphene, Xu Zhang, Gaopei Pan, etc. Phys. Rev. B 107, L241105 (2023)

Non-chiral simulation is in process...

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UMich

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UCAS

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UofT

Heqiu Li



Conclusions

- 1. Berry curvature hotspot is easy to tune in flat band materials, so that non-linear Hall signal can be sensitive to gate voltage (e.g., TBG at non-magic angle).
- 2. TBG at magic angle, assuming spin-valley polarizing at filling $\nu = \pm 3$, evolves from QAH to semimetal departing from chiral limit.
- 3. TBG at magic angle, assuming flat-chiral limit at filling $\nu = \pm 1$, is QAH ground state with Chern number 1. Simulation for non-chiral case is in process.

Thanks!